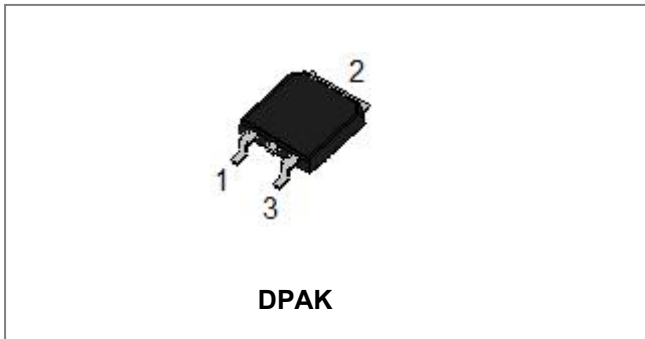
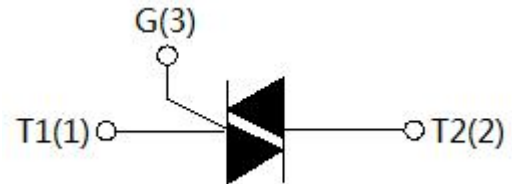


SX040K Sensitive gate SCRs



Circuit Diagram



Description

The SX040K provide high dv/dt rate with strong resistance to electromagnetic interface. They are especially recommended for use on straight hair, igniter etc.

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|---|--------------|---------------|-------------|------------------|
| Storage junction temperature range | T_J | - | -40 to +110 | °C |
| Operating junction temperature range | T_{stg} | - | -40 to +150 | °C |
| Repetitive peak off-state voltage | V_{DRM} | - | 600 | V |
| Repetitive peak reverse voltage | V_{RRM} | - | 600 | V |
| RMS on-state current | $I_{(TRMS)}$ | DPAK(TC=90°C) | 4 | A |
| Non repetitive surge peak on-state current (tp=10ms) | I_{TSM} | - | 30 | A |
| I ² t value for fusing (tp=10ms) | I^2t | - | 4.5 | A ² s |
| Critical rate of rise of on-state current | dI/dt | - | 50 | A/μs |
| Peak gate current (tp=20μs, T _J =110°C) | I_{GM} | - | 1.2 | A |
| Peak gate power (tp=20μs, T _J =110°C) | P_{GM} | - | 2 | W |
| Average gate power dissipation(T _J =110°C) | $P_{G(AV)}$ | - | 0.2 | W |

Electrical Characteristics(T_J=25°C unless otherwise specified)

| Symbol | Condition | Min. | Typ. | Max. | Units |
|----------|--|------|------|------|-------|
| I_{GT} | $V_D=12V R_L=33\Omega$ | - | 50 | 200 | μA |
| V_{GT} | | - | 0.6 | 0.8 | V |
| V_{GD} | $V_D=V_{DRM} T_J=110^\circ C$ | 0.2 | - | - | V |
| I_L | $I_G=1.2 I_{GT}$ | - | - | 6 | mA |
| I_H | $I_T=0.05A$ | - | - | 5 | mA |
| dV/dt | $V_D=2/3V_{DRM} T_J=110^\circ C R_{GK}=1K\Omega$ | 10 | - | - | V/μs |

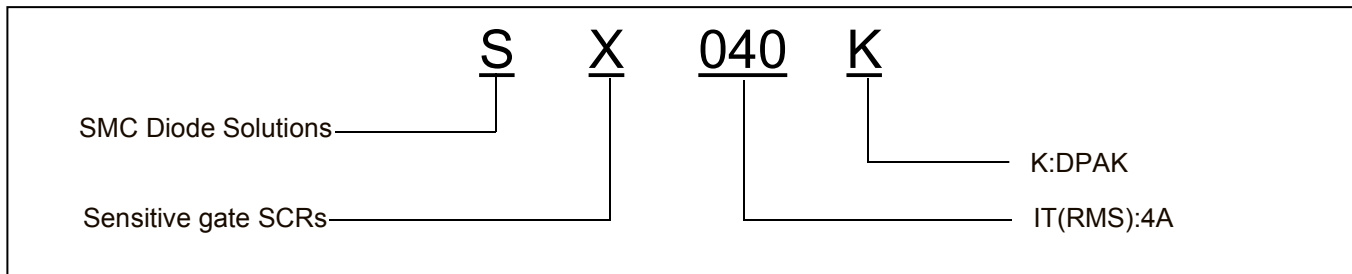
Static Characteristics

| Symbol | Condition | Max. | Units |
|-----------|---|------|---------|
| V_{TM} | $I_{TM}=8A$ $t_p=380\mu s$, $T_j=25^\circ C$ | 1.5 | V |
| I_{DRM} | $V_D=V_{DRM}$ $V_R=V_{RRM}$, $T_j=25^\circ C$ | 5 | μA |
| I_{RRM} | $V_D=V_{DRM}$ $V_R=V_{RRM}$, $T_j=110^\circ C$ | 100 | μA |

Thermal Resistances

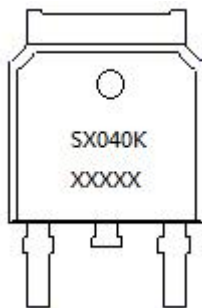
| Symbol | Condition | Value | Units |
|---------------|--------------------------|-------|--------------|
| $R_{th(j-c)}$ | Junction to case DPAK | 6.5 | $^\circ C/W$ |

Ordering Information



| Device | Package | Shipping |
|----------|---------|---------------|
| SX040K | DPAK | 2500pcs/ reel |
| SX040KTR | DPAK | 2500pcs/ reel |

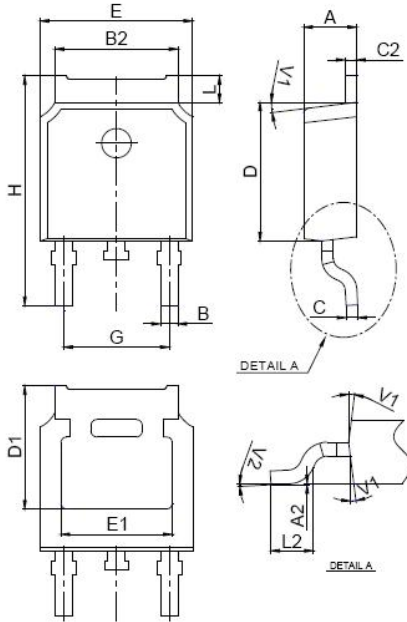
Marking Diagram



Where XXXXX is YYWWL

S = SMC
X = Sensitive gate SCRs
040 = Forward Current (4A)
K = Package type
YY = Year
WW = Week
L = Lot Number

Mechanical Dimensions DPAK



| SYMBOL | Millimeters | | | Inches | | |
|--------|-------------|------|-------|----------|------|-------|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 2.10 | | 2.50 | 0.083 | | 0.098 |
| A2 | 0 | | 0.10 | 0 | | 0.004 |
| B | 0.66 | | 0.86 | 0.026 | | 0.034 |
| B2 | 5.18 | | 5.48 | 0.202 | | 0.216 |
| C | 0.40 | | 0.60 | 0.016 | | 0.024 |
| C2 | 0.44 | | 0.58 | 0.017 | | 0.023 |
| D | 5.90 | | 6.30 | 0.232 | | 0.248 |
| D1 | 5.30REF | | | 0.209REF | | |
| E | 6.40 | | 6.80 | 0.252 | | 0.268 |
| E1 | 4.63 | | | 0.182 | | |
| G | 4.47 | | 4.67 | 0.176 | | 0.184 |
| H | 9.50 | | 10.70 | 0.374 | | 0.421 |
| L | 1.09 | | 1.21 | 0.043 | | 0.048 |
| L2 | 1.35 | | 1.65 | 0.053 | | 0.065 |
| V1 | 7° | | | 7° | | |
| V2 | 0° | | 6° | 0° | | 6° |

Ratings and Characteristics Curves

FIG.1: Maximum power dissipation versus RMS on-state current

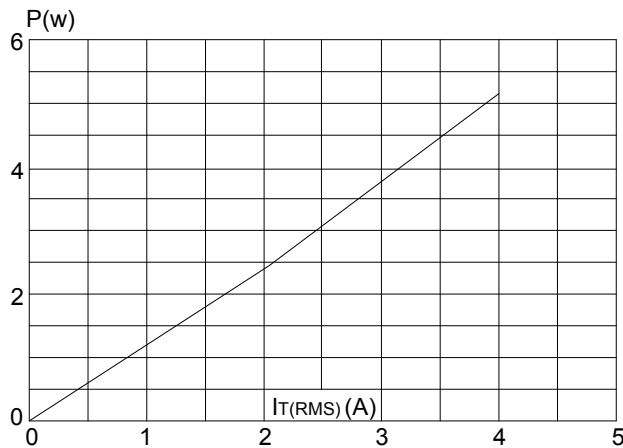


FIG.2: RMS on-state current versus case temperature

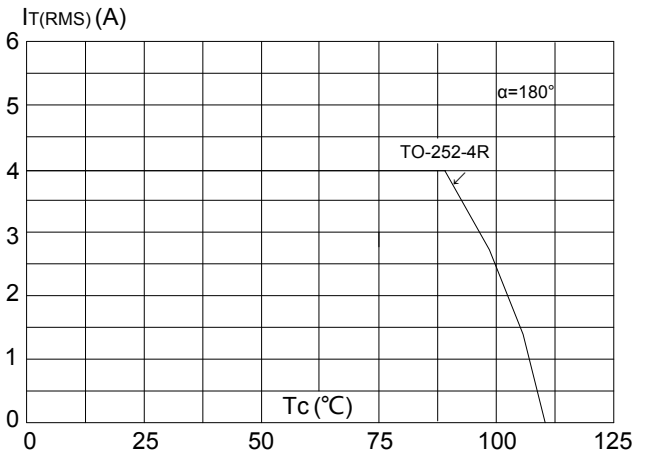


FIG.3: Surge peak on-state current versus number of cycles

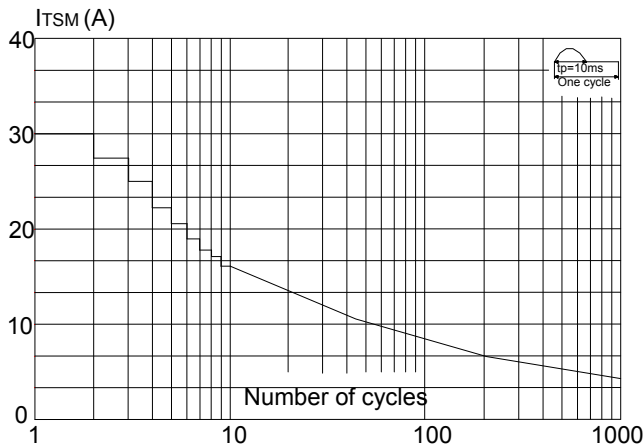


FIG.4: On-state characteristics (maximum values)

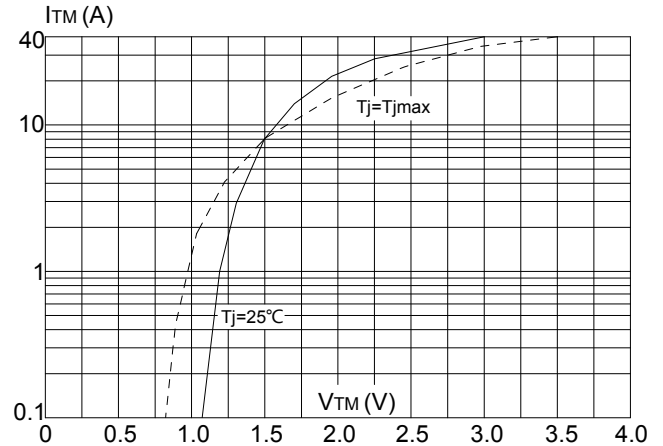


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of I^2t ($di/dt < 50\text{A}/\mu\text{s}$)

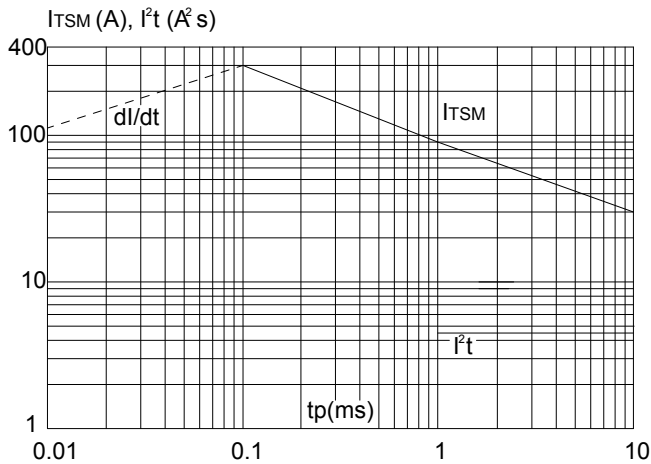
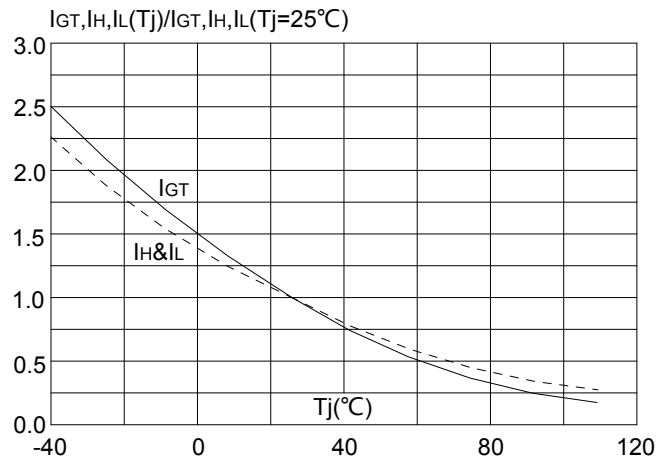


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



Technical Data
Data Sheet N2045, Rev.-



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